Preferred Devices

SWITCHMODE [™] **Power Rectifiers**

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 and 60 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-247 Package
- High Voltage Capability to 600 V
- Low Forward Drop
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating Specified @ Both Case and Ambient Temperatures
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- Pb-Free Packages are Available*

Mechanical Characteristics:

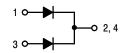
- Case: Epoxy, Molded
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 Units Per Plastic Tube



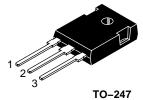
ON Semiconductor®

http://onsemi.com

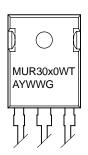
ULTRAFAST RECTIFIERS 30 AMPERES, 200-600 VOLTS



MARKING DIAGRAM



CASE 340L PLASTIC



MUR30x0WT = Device Code x = 2 or 6

A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MUR3020WT	TO-247	30 Units/Rail
MUR3020WTG	TO-247 (Pb-Free)	30 Units/Rail
MUR3060WT	TO-247	30 Units/Rail
MUR3060WTG	TO-247 (Pb-Free)	30 Units/Rail

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	MUR3020WT	MUR3060WT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	600	V
Average Rectified Forward Current @ 145°C Total Device	I _{F(AV)}	15 30		А
Peak Repetitive Surge Current (Rated V_R , Square Wave, 20 kHz, $T_C = 145$ °C)	I _{FM}	30		А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I _{FSM}	200	150	А
Operating Junction and Storage Temperature	T _J , T _{stg}	- 65 to +175		°C

THERMAL CHARACTERISTICS (Per Leg)

Maximum Thermal Resistance,			°C/W
Junction-to-CaseJunction-to-Ambient	$R_{ hetaJC} \ R_{ hetaJA}$	1.5 40	

ELECTRICAL CHARACTERISTICS (Per Leg)

Maximum Instantaneous Forward Voltage (Note 1) (I _F = 15 Amp, T_C = 150°C) (I _F = 15 Amp, T_C = 25°C)	V _F	0.85 1.05	1.4 1.7	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_J = 150^{\circ}C$) (Rated DC Voltage, $T_J = 25^{\circ}C$)	i _R	500 10	1000 10	μΑ
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 Amps/μs)	t _{rr}	35	60	ns

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

MUR3020WT

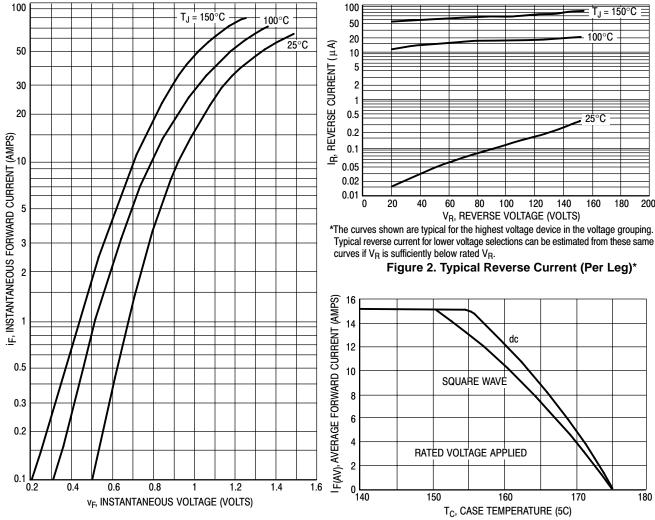


Figure 1. Typical Forward Voltage (Per Leg)

Figure 3. Current Derating, Case (Per Leg)

180

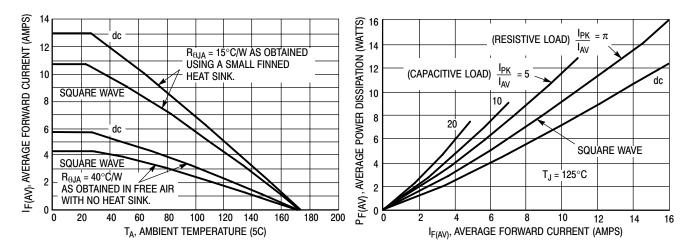


Figure 4. Current Derating, Ambient (Per Leg)

Figure 5. Power Dissipation (Per Leg)

MUR3060WT

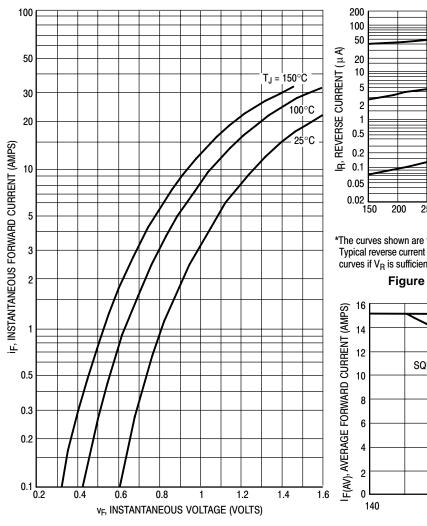
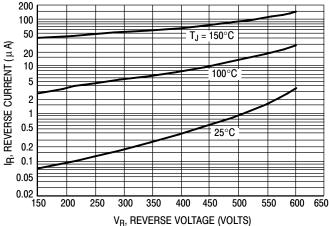


Figure 6. Typical Forward Voltage (Per Leg)



*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

Figure 7. Typical Reverse Current (Per Leg)*

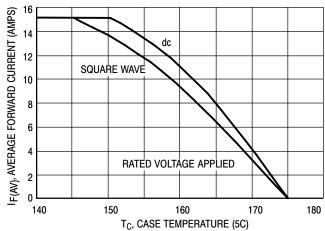


Figure 8. Current Derating, Case (Per Leg)

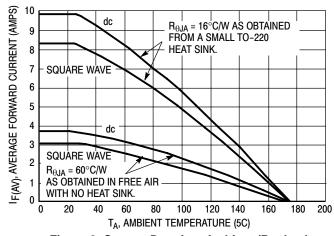


Figure 9. Current Derating, Ambient (Per Leg)

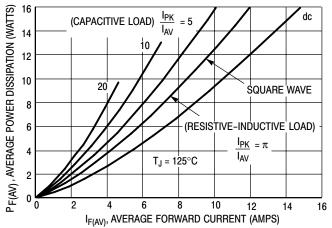


Figure 10. Power Dissipation (Per Leg)

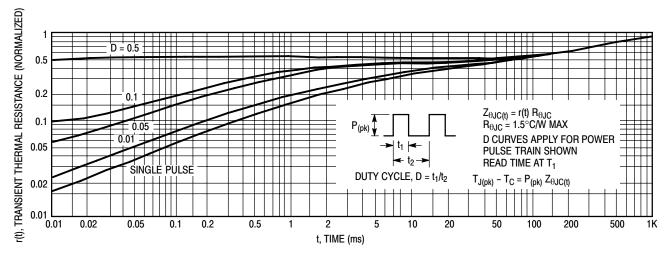


Figure 11. Thermal Response

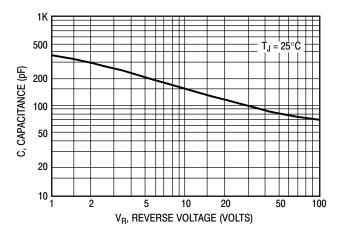
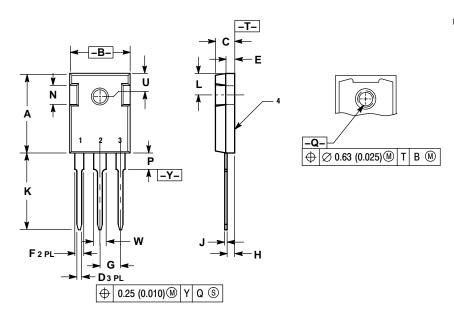


Figure 12. Typical Capacitance (Per Leg)

PACKAGE DIMENSIONS

TO-247 PSI CASE 340L-02 ISSUE D



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 5M 1992
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	20.32	21.08	0.800	8.30	
В	15.75	16.26	0.620	0.640	
С	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
Е	2.20	2.60	0.087	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45 BSC		0.215 BSC		
Н	1.50	2.49	0.059	0.098	
J	0.40	0.80	0.016	0.031	
K	20.06	20.83	0.790	0.820	
L	5.40	6.20	0.212	0.244	
N	4.32	5.49	0.170	0.216	
Р	-	4.50		0.177	
Q	3.55	3.65	0.140	0.144	
U	6.15 BSC		0.242 BSC		
W	2.87	3.12	0.113	0.123	

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